Maximum Ratings (TJ = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, $T_J = -40^{\circ}$ to 125°C)	MAC8DG MAC8MG MAC8NG	V _{drm} , V _{rrm}	400 600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_c = 10$	I _{T (RMS)}	8.0	А	
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T_c = 125°C)		I _{TSM}	80	А
Circuit Fusing Consideration (t = 8.3 ms)		l²t	26	A ² sec
Peak Gate Power (Pulse Width \leq 1.0 µs, T _c = 80°C)	P _{GM}	16	W	
Average Gate Power (t=8.3ms, $T_{J} = 80^{\circ}$ C)		P _{G(AV)}	0.35	W
Operating Junction Temperature Range		TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DENM} and V_{BENM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance,	Junction-to-Case (AC) Junction-to-Ambient	R _{ejc} R _{eja}	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purpose	s, 1/8" from case for 10 seconds	TL	260	°C

Electrical Characteristics - OFF ($TJ = 25^{\circ}C$ unless otherwise noted ; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current	T ₁ = 25°C	I _{DRM} ,	-	-	0.01	mA
$(V_{D} = V_{DRM} = V_{RRM}; \text{ Gate Open})$	T_ = 125°C	I	-	-	2.0	ШA

Electrical Characteristics - ON (TJ = 25° C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak On–State Voltage (Note 4) ($I_{TM} = \pm 6.0 \text{ A}$)		V _{TM}	-	1.3	1.6	V
Gate Trigger Current	MT2(+), G(+)		5.0	13	35.0	
(Continuous dc)	MT2(+), G(-)	I _{gt}	5.0	16	35.0	mA
$(V_{D} = 12 V, R_{L} = 100 \Omega)$	MT2(-), G(-)		5.0	18	35.0	
Holding Current ($V_p = 12 V$, Gate Open, Initiating Current = ±150 mA	.))	I _H	-	20	40	mA
	MT2(+), G(+)		_	20	50	mA
Latching Current ($V_p = 24 V$, $I_c = 35 mA$)	MT2(+), G(-)	I _L	_	30	80	
$(v_{\rm D} - 24v), r_{\rm G} - 33 m/r)$	MT2(-), G(-)		_	20	50	
	MT2(+), G(+)		0.5	0.69	1.5	V
Gate Trigger Voltage ($V_p = 12 V, R_1 = 100 \Omega$)	MT2(+), G(-)	V _{GT}	0.5	0.77	1.5	
$(v_{\rm D} - 12 v, 11_{\rm L} - 100 \Omega)$	MT2(-), G(-)		0.5	0.72	1.5	
Gate Non-Trigger Voltage	MT2(+), G(+)		0.2	-	-	
(T ₁ = 125°C)	MT2(+), G(-)	V _{gd}	0.2	-	-	V
$(V_{D} = 12 \text{ V}, \text{ R}_{L} = 100 \Omega)$	MT2(-), G(-)	00	0.2	-	-	
2. Indicates Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.						



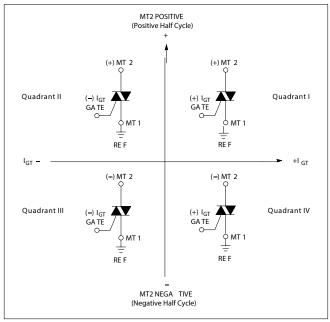
Dynamic Characteristics

Characteristic	Symbol	Min	Тур	Мах	Unit
Rate of Change of Commutating Current See Figure 10.(V _D = 400 V, I _{TM} = 4.4 A, Commutating dv/dt = 18 V/µs,Gate Open, T _J = 125°C, f = 250 Hz, No Snubber) C _I = 10 μ F L _I = 40 mH	(dv/dt)c	6.5	-	-	A/ms
Critical Rate of Rise of Off-State Voltage ($V_{D} = Rated V_{DRM}$, Exponential Waveform, Gate Open, $T_{J} = 125^{\circ}C$)	dV/dt	250	_	_	V/µs

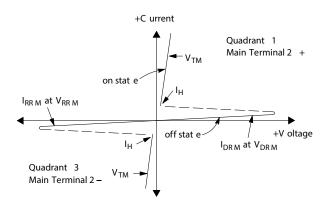
Voltage Current Characteristic of SCR

Symbol	Parameter
V _{drm}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current

Quadrant Definitions for a Triac



All polarities are referenced to MT1. With in-phase signals (using standard AC lines) quadrants I and III are used





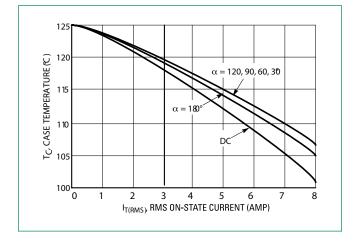


Figure 1. RMS Current Derating

Figure 2. On-State Power Dissipation

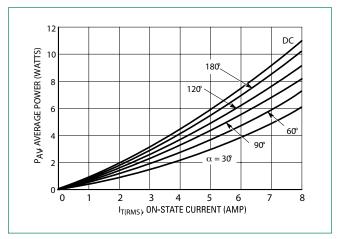


Figure 4. Thermal Response

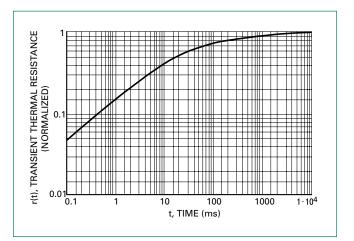


Figure 5. Hold Current Variation

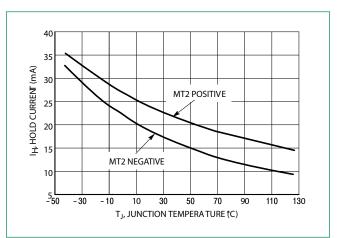


Figure 3. On–State Characteristics

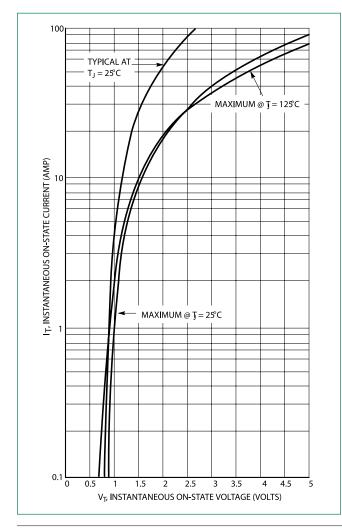


Figure 6. Gate Trigger Current Variation

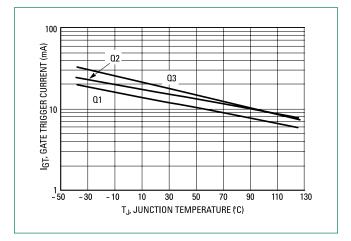


Figure 8. Critical Rate of Rise of Off-State Voltage (Exponential)

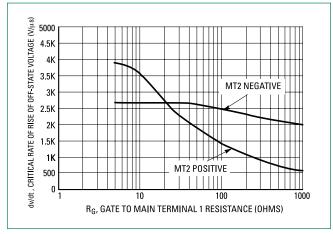
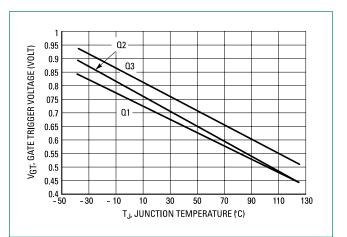


Figure 7. Gate Trigger Voltage Variation





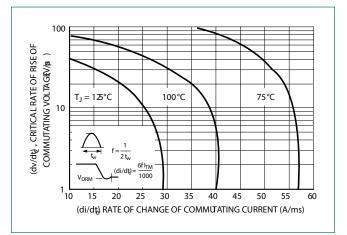
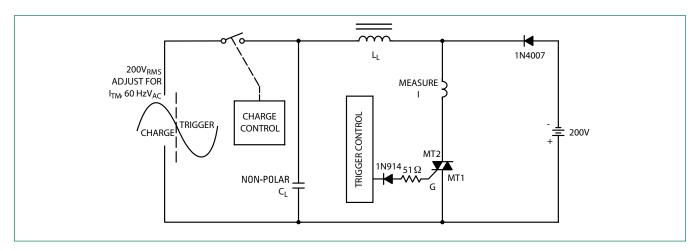


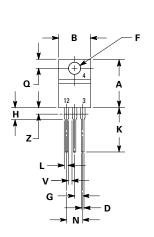
Figure 10. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)

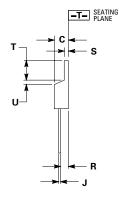


Note: Component values are for verification of rated (di/dt)_c. See AN1048 for additional information

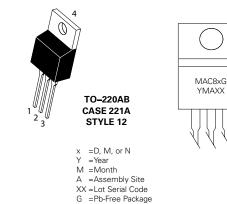


Dimensions





Part Marking System



Dim	Inc	hes	Millin	neters
DIM	Min	Мах	Min	Мах
Α	0.590	0.620	14.99	15.75
В	0.380	0.420	9.65	10.67
С	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.41	2.67
н	0.110	0.130	2.79	3.30
J	0.018	0.024	0.46	0.61
К	0.540	0.575	13.72	14.61
L	0.060	0.075	1.52	1.91
Ν	0.195	0.205	4.95	5.21
Q	0.105	0.115	2.67	2.92
R	0.085	0.095	2.16	2.41
S	0.045	0.060	1.14	1.52
т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Z		0.080		2.04

Pin Assignment				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	No Connection			

Ordering Information

Device	Package	Shipping
MAC8DG		
MAC8MG	TO-220AB (Pb-Free)	1000 Units / Box
MAC8NG	(1.5.1.66)	

1. Dimensioning and tolerancing per ansi y14.5m, 1982.

2. Controlling dimension: inch.

 $\textbf{3. Dimension} \ \textbf{z} \ \textbf{defines} \ \textbf{a} \ \textbf{zone} \ \textbf{where all body and lead irregularities are allowed}.$

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